

# Bin Amin

## List of Publications by Citations

**Source:** <https://exaly.com/author-pdf/8636458/bin-amin-publications-by-citations.pdf>

**Version:** 2024-04-27

This document has been generated based on the publications and citations recorded by exaly.com. For the latest version of this publication list, visit the link given above.

The third column is the impact factor (IF) of the journal, and the fourth column is the number of citations of the article.

75  
papers

2,059  
citations

24  
h-index

44  
g-index

80  
ext. papers

2,623  
ext. citations

3.2  
avg, IF

5.45  
L-index

#	Paper	IF	Citations
75	Strain engineering of WS <sub>2</sub> , WSe <sub>2</sub> , and WTe <sub>2</sub> . <i>RSC Advances</i> , <b>2014</b> , 4, 34561	3.7	216
74	Heterostructures of transition metal dichalcogenides. <i>Physical Review B</i> , <b>2015</b> , 92,	3.3	146
73	Layered graphene/GaS van der Waals heterostructure: Controlling the electronic properties and Schottky barrier by vertical strain. <i>Applied Physics Letters</i> , <b>2018</b> , 113, 171605	3.4	141
72	Ab initio study of the bandgap engineering of Al <sub>1-x</sub> Ga <sub>x</sub> N for optoelectronic applications. <i>Journal of Applied Physics</i> , <b>2011</b> , 109, 023109	2.5	129
71	Rashba spin splitting and photocatalytic properties of Ge <sub>1-x</sub> MS <sub>2</sub> (M=Mo, W) van der Waals heterostructures. <i>Physical Review B</i> , <b>2019</b> , 100,	3.3	92
70	Graphene/WSeTe van der Waals heterostructure: Controllable electronic properties and Schottky barrier via interlayer coupling and electric field. <i>Applied Surface Science</i> , <b>2020</b> , 507, 145036	6.7	92
69	Investigation of structural and optoelectronic properties of BaThO <sub>3</sub> . <i>Optical Materials</i> , <b>2011</b> , 33, 553-557	3.3	87
68	Optoelectronic and solar cell applications of Janus monolayers and their van der Waals heterostructures. <i>Physical Chemistry Chemical Physics</i> , <b>2019</b> , 21, 18612-18621	3.6	77
67	Materials properties of out-of-plane heterostructures of MoS <sub>2</sub> -WSe <sub>2</sub> and WS <sub>2</sub> -MoSe <sub>2</sub> . <i>Applied Physics Letters</i> , <b>2016</b> , 108, 063105	3.4	60
66	Electronic structure, optical and photocatalytic performance of SiC-MX (M = Mo, W and X = S, Se) van der Waals heterostructures. <i>Physical Chemistry Chemical Physics</i> , <b>2018</b> , 20, 24168-24175	3.6	60
65	Interfacial characteristics, Schottky contact, and optical performance of a graphene/Ga <sub>2</sub> SSe van der Waals heterostructure: Strain engineering and electric field tunability. <i>Physical Review B</i> , <b>2020</b> , 102,	3.3	55
64	Structural and electronic properties of a van der Waals heterostructure based on silicene and gallium selenide: effect of strain and electric field. <i>Physical Chemistry Chemical Physics</i> , <b>2018</b> , 20, 27856-27864	3.6	54
63	Van der Waals heterostructures of P, BSe, and SiC monolayers. <i>Journal of Applied Physics</i> , <b>2019</b> , 125, 094301	2.5	45
62	Interlayer coupling and electric field controllable Schottky barriers and contact types in graphene/PbI <sub>2</sub> heterostructures. <i>Physical Review B</i> , <b>2020</b> , 101,	3.3	45
61	Van der Waals graphene/g-GaSe heterostructure: Tuning the electronic properties and Schottky barrier by interlayer coupling, biaxial strain, and electric gating. <i>Journal of Alloys and Compounds</i> , <b>2018</b> , 750, 765-773	5.7	45
60	First principles study of the electronic properties and Schottky barrier in vertically stacked graphene on the Janus MoSeS under electric field. <i>Computational Materials Science</i> , <b>2018</b> , 153, 438-444	3.2	45
59	Intriguing electronic structures and optical properties of two-dimensional van der Waals heterostructures of Zr <sub>2</sub> CT <sub>2</sub> (T = O, F) with MoSe <sub>2</sub> and WSe <sub>2</sub> . <i>Journal of Materials Chemistry C</i> , <b>2018</b> , 6, 2830-2839	7.1	43

58	Electronic structure of cubic perovskite SnTaO <sub>3</sub> . <i>Intermetallics</i> , <b>2012</b> , 31, 287-291	3.5	41
57	Strain engineering of electronic structures and photocatalytic responses of MXenes functionalized by oxygen. <i>Physical Chemistry Chemical Physics</i> , <b>2017</b> , 19, 14738-14744	3.6	40
56	Cr-Doped III $\bar{V}$ Nitrides: Potential Candidates for Spintronics. <i>Journal of Electronic Materials</i> , <b>2011</b> , 40, 1428-1436	1.9	38
55	Band alignment and optical features in Janus-MoSeTe/X(OH) (X = Ca, Mg) van der Waals heterostructures. <i>Physical Chemistry Chemical Physics</i> , <b>2019</b> , 21, 25849-25858	3.6	36
54	Tailoring the structural and electronic properties of an SnSe/MoS van der Waals heterostructure with an electric field and the insertion of a graphene sheet. <i>Physical Chemistry Chemical Physics</i> , <b>2019</b> , 21, 22140-22148	3.6	32
53	Vertical strain and electric field tunable electronic properties of type-II band alignment C <sub>2</sub> N/InSe van der Waals heterostructure. <i>Chemical Physics Letters</i> , <b>2019</b> , 716, 155-161	2.5	30
52	Electronic properties and enhanced photocatalytic performance of van der Waals heterostructures of ZnO and Janus transition metal dichalcogenides. <i>Physical Chemistry Chemical Physics</i> , <b>2020</b> , 22, 10351-10359 <sup>26</sup>	3.6	26
51	CsNaGaBr: a new lead-free and direct band gap halide double perovskite.. <i>RSC Advances</i> , <b>2020</b> , 10, 17444-17451 <sup>23</sup>	3.7	23
50	Major enhancement of the thermoelectric performance in Pr/Nb-doped SrTiO <sub>3</sub> under strain. <i>Applied Physics Letters</i> , <b>2013</b> , 103, 031907	3.4	23
49	Theoretical exploration of the potential applications of Sc-based MXenes. <i>Physical Chemistry Chemical Physics</i> , <b>2017</b> , 19, 32253-32261	3.6	23
48	Electric field tunable electronic properties of P-ZnO and SiC-ZnO van der Waals heterostructures. <i>Computational Materials Science</i> , <b>2019</b> , 164, 166-170	3.2	20
47	Theoretical investigation of electronic structure and thermoelectric properties of MX <sub>2</sub> (M=Zr, Hf; X=S, Se) van der Waals heterostructures. <i>Journal of Physics and Chemistry of Solids</i> , <b>2019</b> , 126, 304-309	3.9	19
46	Molecular distortion and charge transfer effects in ZnPc/Cu(111). <i>Scientific Reports</i> , <b>2013</b> , 3,	4.9	17
45	Effects of different surface functionalization on the electronic properties and contact types of graphene/functionalized-GeC van der Waals heterostructures. <i>Physical Chemistry Chemical Physics</i> , <b>2020</b> , 22, 7952-7961	3.6	15
44	Strain and electric field tunable electronic properties of type-II band alignment in van der Waals GaSe/MoSe <sub>2</sub> heterostructure. <i>Chemical Physics</i> , <b>2019</b> , 521, 92-99	2.3	15
43	Theoretical investigation of half-metallicity in Co/Ni substituted AlN. <i>International Journal of Quantum Chemistry</i> , <b>2012</b> , 112, 882-888	2.1	12
42	Electronic structure, optoelectronic properties and enhanced photocatalytic response of GaN-GeC van der Waals heterostructures: a first principles study.. <i>RSC Advances</i> , <b>2020</b> , 10, 24127-24133	3.7	11
41	van der Waals heterostructures based on MSSe (M = Mo, W) and graphene-like GaN: enhanced optoelectronic and photocatalytic properties for water splitting. <i>Physical Chemistry Chemical Physics</i> , <b>2020</b> , 22, 20704-20711	3.6	11

40	Influence of strain on specific features of MoX <sub>2</sub> (X = S, Se, Te) monolayers. <i>Physica B: Condensed Matter</i> , <b>2018</b> , 545, 113-118	2.8	11
39	Tri-layered van der Waals heterostructures based on graphene, gallium selenide and molybdenum selenide. <i>Journal of Applied Physics</i> , <b>2019</b> , 125, 225304	2.5	10
38	Effects of electric field and strain engineering on the electronic properties, band alignment and enhanced optical properties of ZnO/Janus ZrSSe heterostructures.. <i>RSC Advances</i> , <b>2020</b> , 10, 9824-9832	3.7	9
37	A first-principles study of electronic structure and photocatalytic performance of GaN-MX (M = Mo, W; X= S, Se) van der Waals heterostructures.. <i>RSC Advances</i> , <b>2020</b> , 10, 24683-24690	3.7	9
36	Robust half-metallicity of AlCoN and AlNiN. <i>International Journal of Quantum Chemistry</i> , <b>2012</b> , 112, 2668-2674	2.6	9
35	Van der Waals heterostructures of SiC and Janus MSSe (M = Mo, W) monolayers: a first principles study.. <i>RSC Advances</i> , <b>2020</b> , 10, 25801-25807	3.7	8
34	ELECTRONIC BAND STRUCTURE, OPTICAL, THERMAL AND BONDING PROPERTIES OF XMg <sub>2</sub> O <sub>4</sub> (X = Si, Ge) SPINEL COMPOUNDS. <i>International Journal of Modern Physics B</i> , <b>2013</b> , 27, 1350082	1.1	8
33	STRUCTURAL, ELASTIC, ELECTRONIC, CHEMICAL BONDING AND OPTICAL PROPERTIES OF M <sub>2</sub> Se (M = Li, Na, K, Rb) THROUGH FIRST PRINCIPLE STUDY. <i>International Journal of Modern Physics B</i> , <b>2013</b> , 27, 1350170	1.1	8
32	Structural, elastic, thermal and electronic properties of M <sub>2</sub> X (M = Sr, Ba and X = Si, Ge, Sn) compounds in anti-fluorite structure: first principle calculations. <i>Indian Journal of Physics</i> , <b>2015</b> , 89, 369-375	1.4	7
31	Electronic and optoelectronic properties of van der Waals heterostructure based on graphene-like GaN, blue phosphorene, SiC, and ZnO: A first principles study. <i>Journal of Applied Physics</i> , <b>2020</b> , 127, 245302	2.5	7
30	Computational insights into structural, electronic and optical characteristics of GeC/CN van der Waals heterostructures: effects of strain engineering and electric field.. <i>RSC Advances</i> , <b>2020</b> , 10, 2967-2974	2.7	7
29	Electronic and photocatalytic properties of two-dimensional boron phosphide/SiC van der Waals heterostructure with direct type-II band alignment: a first principles study.. <i>RSC Advances</i> , <b>2020</b> , 10, 32027-32033	2.7	7
28	Type-I band alignment of BX-ZnO (X = As, P) van der Waals heterostructures as high-efficiency water splitting photocatalysts: a first-principles study.. <i>RSC Advances</i> , <b>2020</b> , 10, 44545-44550	3.7	7
27	Understanding the electronic properties, contact types and optical performances in graphene/InN heterostructure: Role of electric gating. <i>Diamond and Related Materials</i> , <b>2020</b> , 106, 107851	3.5	7
26	Thermoelectric properties of the misfit cobaltate Ca <sub>3</sub> Co <sub>4</sub> O <sub>9</sub> . <i>Applied Physics Letters</i> , <b>2017</b> , 110, 233505	3.4	6
25	Van der Waals heterostructures of blue phosphorene and scandium-based MXenes monolayers. <i>Journal of Applied Physics</i> , <b>2019</b> , 126, 143101	2.5	6
24	First-principles study of the electronic structures and optical and photocatalytic performances of van der Waals heterostructures of SiS, P and SiC monolayers.. <i>RSC Advances</i> , <b>2021</b> , 11, 14263-14268	3.7	6
23	Effect of strain on structural and electronic properties, and thermoelectric response of MXY (M=Zr, Hf and Pt; X/Y=S, Se) vdW heterostructures; A first principles study. <i>Journal of Solid State Chemistry</i> , <b>2021</b> , 299, 122189	3.3	6

22	Strain and electric field engineering of band alignment in InSe/Ca(OH) <sub>2</sub> heterostructure. <i>Chemical Physics Letters</i> , <b>2019</b> , 732, 136649	2.5	5
21	Electronic structures, and optical and photocatalytic properties of the BPBSe van der Waals heterostructures. <i>New Journal of Chemistry</i> , <b>2020</b> , 44, 14964-14969	3.6	5
20	Strain engineering and electric field tunable electronic properties of Ti <sub>2</sub> CO <sub>2</sub> MXene monolayer. <i>Materials Research Express</i> , <b>2019</b> , 6, 065910	1.7	4
19	First principles study of electronic and optical properties and photocatalytic performance of GaN-SiS van der Waals heterostructure.. <i>RSC Advances</i> , <b>2021</b> , 11, 32996-33003	3.7	4
18	Strain engineering of the electro-optical and photocatalytic properties of single-layered Janus MoSSe: First principles calculations. <i>Optik</i> , <b>2020</b> , 224, 165503	2.5	4
17	Stacking effects in van der Waals heterostructures of blueP and Janus XYO (X = Ti, Zr, Hf; Y = S, Se) monolayers.. <i>RSC Advances</i> , <b>2021</b> , 11, 12189-12199	3.7	4
16	Strain engineering of Janus ZrSSe and HfSSe monolayers and ZrSSe/HfSSe van der Waals heterostructure. <i>Chemical Physics Letters</i> , <b>2021</b> , 776, 138689	2.5	4
15	Realization of noble heterobilayers with enhanced optoelectronic properties. <i>Applied Surface Science</i> , <b>2020</b> , 505, 144530	6.7	3
14	Intriguing electronic structure and photocatalytic performance of blueP-SMSe and blueP-SeMS (M = Mo, W) van der Waals heterostructures.. <i>RSC Advances</i> , <b>2020</b> , 10, 38114-38119	3.7	3
13	Optoelectronic and photocatalytic applications of hBP-XMY (M = Mo, W; (X Y) = S, Se, Te) van der Waals heterostructures. <i>Physical Chemistry Chemical Physics</i> , <b>2020</b> , 22, 23028-23037	3.6	3
12	Van der Waal heterostructure based on BY(Y As, P) and MX <sub>2</sub> (M Mo, W; X S, Se) monolayers. <i>Applied Surface Science</i> , <b>2021</b> , 568, 150846	6.7	3
11	Electronic structure and optical performance of Pbl <sub>2</sub> /SnSe <sub>2</sub> heterostructure. <i>Chemical Physics</i> , <b>2020</b> , 533, 110736	2.3	2
10	First-principles study of metal-semiconductor contact between MX <sub>2</sub> (M = Nb, Pt; X = S, Se) monolayers. <i>Physics Letters, Section A: General, Atomic and Solid State Physics</i> , <b>2019</b> , 383, 125867	2.3	2
9	Intriguing electronic and optical properties of M <sub>2</sub> CX <sub>2</sub> (M = Mo, W; X = O, F) MXenes and their van der Waals heterostructures. <i>Chemical Physics Letters</i> , <b>2019</b> , 731, 136614	2.5	2
8	Intriguing electronic, optical and photocatalytic performance of BSe, MCO monolayers and BSe-MCO (M = Ti, Zr, Hf) van der Waals heterostructures.. <i>RSC Advances</i> , <b>2021</b> , 12, 42-52	3.7	2
7	Van der Waals heterostructure of Janus transition metal dichalcogenides monolayers (WSSe-WX <sub>2</sub> (X=S, Se)). <i>Chemical Physics</i> , <b>2021</b> , 549, 111252	2.3	2
6	Effects of La and Ce doping on electronic structure and optical properties of janus MoSSe monolayer. <i>Superlattices and Microstructures</i> , <b>2021</b> , 151, 106841	2.8	1
5	Two-dimensional blue phosphoreneBAs vdW heterostructure with optical and photocatalytic properties: a first-principles study. <i>RSC Advances</i> , <b>2021</b> , 11, 13025-13029	3.7	1

4	Strain effect on the electronic and photocatalytic properties of GaN-MSSe (M=Mo, W). <i>Journal of Solid State Chemistry</i> , <b>2022</b> , 306, 122798	3.3	○
3	Van der Waal heterostructure of hBAs and XMY (M = Mo, W; (XY) = S, Se) monolayers. <i>Chemical Physics</i> , <b>2022</b> , 552, 111374	2.3	○
2	First principles study of optoelectronic and photocatalytic performance of novel transition metal dipnictide XP (X = Ti, Zr, Hf) monolayers.. <i>RSC Advances</i> , <b>2022</b> , 12, 11202-11206	3.7	○
1	Intriguing interfacial characteristics of the CS contact with MX (M = Mo, W; X = S, Se, Te) and MXY ((X Y) = S, Se, Te) monolayers.. <i>RSC Advances</i> , <b>2022</b> , 12, 12292-12302	3.7	○